DISCRETE SEMICONDUCTORS

DATA SHEET

BGY115A; BGY115B; BGY115C/P; BGY115D UHF amplifier modules

Product specification Supersedes data of May 1994 File under Discrete Semiconductors, SC09 1996 May 13





UHF amplifier modules

BGY115A; **BGY115B**; **BGY115C/P**; **BGY115D**

FEATURES

- 6 V nominal supply voltage1996 May 13
- 1.2 W output power (BGY115A, BGY115B and BGY115D)
- 1.4 W output power (BGY115C/P)
- Easy control of output power by DC voltage
- · SMD outline.

APPLICATIONS

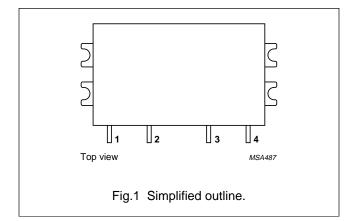
 Hand-held transmitting equipment operating in the 824 to 849 MHz, 872 to 905 MHz, 890 to 915 MHz and 902 to 928 MHz frequency ranges.

DESCRIPTION

The BGY115A, BGY115B, BGY115C/P and BGY115D are three-stage UHF amplifier modules. Each module consists of three NPN silicon planar transistor chips mounted together with matching and bias circuit components on a metallized ceramic substrate.

PINNING - SOT321A

PIN	DESCRIPTION
1	RF input
2	V _C
3	V _S
4	RF output
Flange	ground



QUICK REFERENCE DATA

RF performance at $T_{mb} = 25$ °C.

TYPE NUMBER	MODE OF OPERATION	f (MHz)	V _S (V)	P _L (W)	G _p (dB)	η (%)	Z _S ; Z _L (Ω)
BGY115A	CW	824 to 849	6	1.2	≥27.8	typ. 50	50
BGY115B	CW	872 to 905	6	1.2	≥27.8	typ. 50	50
BGY115C/P	CW	890 to 915	6	1.4	≥28.5	typ. 50	50
BGY115D	CW	902 to 928	6	1.2	≥27.8	typ. 50	50

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vs	DC supply voltage			
	BGY115A, BGY115B, BGY115D	_	8.5	V
	BGY115C/P	_	9	V
V _C	DC control voltage	_	4	V
P_{D}	input drive power	_	5	mW
P _L	load power			
	BGY115A, BGY115B, BGY115D	_	1.6	W
	BGY115C/P	_	1.8	W
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-30	+100	°C

UHF amplifier modules

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CHARACTERISTICS

 $Z_S = Z_L = 50~\Omega; P_D = 2~mW; V_S = 6~V; V_C \le 3.5~V; T_{mb} = 25~^{\circ}C;$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency					
	BGY115A		824	-	849	MHz
	BGY115B		872	-	905	MHz
	BGY115C/P		890	-	915	MHz
	BGY115D		902	_	928	MHz
IQ	leakage current	$V_C = 0; P_D < -60 \text{ dBm}$	_	_	100	μΑ
I _C	control current	note 1	_	_	500	μΑ
P_{L}	load power					
	BGY115A, BGY115B, BGY115D		1.2	-	_	W
	BGY115C/P		1.4	-	_	W
G _p	power gain	note 1				
	BGY115A, BGY115B, BGY115D		27.8	-	_	dB
	BGY115C/P		28.5	_	_	dB
η	efficiency	note 1	45	50	_	%
H ₂	second harmonic	note 1	_	_	-40	dBc
H ₃	third harmonic	note 1	_	_	-40	dBc
VSWR _{in}	input VSWR	note 1	_	_	3:1	
	stability	P_D = 0 to 6 dBm; V_S = 4.8 to 8.5 V; V_C = 0 to 3.5 V; VSWR \leq 6 : 1 through all phases; note 2	-	-	-60	dBc
	isolation	$V_C = 0$	_	_	-40	dBm
P _n	noise power	bandwidth = 30 kHz; 45 MHz above f ₀ ; note 1	_	_	-90	dBm
	ruggedness	note 3	no degradation			

Notes

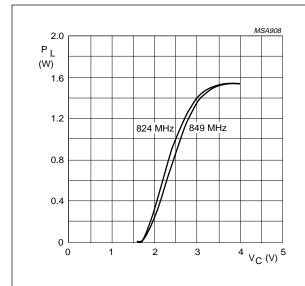
- 1. Adjust V_C for P_L = 1.2 W (BGY115A, BGY115B and BGY115D); P_L = 1.4 W (BGY115C/P).
- 2. Adjust V_C for $P_L \le 1.2$ W (BGY115A, BGY115B and BGY115D); $P_L \le 1.4$ W, $V_S = 4.8$ to 8 V (BGY115C/P).

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3. Adjust V_C for P_L = 1.6 W; V_S = 8.5 V; VSWR \leq 10 : 1; (BGY115A, BGY115B and BGY115D). Adjust V_C for P_L = 1.6 W; V_S = 9 V, VSWR \leq 6 : 1 (BGY115C/P).

UHF amplifier modules

BGY115A; BGY115B; BGY115C/P; BGY115D



 Z_S = Z_L = 50 $\Omega;~P_D$ = 2 mW; V_S = 6 V; T_{mb} = 25 $^{\circ}C.$

Fig.2 Load power as a function of control voltage; BGY115A, typical values.

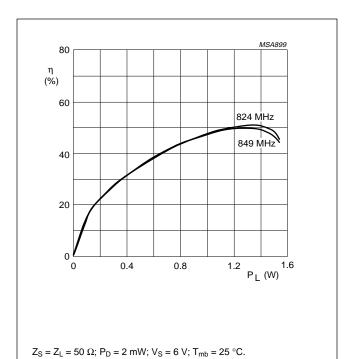
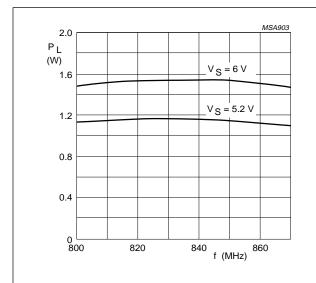
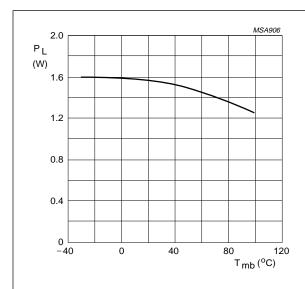


Fig.3 Efficiency as a function of load power; BGY115A, typical values.



 Z_S = Z_L = 50 $\Omega;$ P_D = 2 mW; V_C = 3.5 V; T_{mb} = 25 $^{\circ}C.$

Fig.4 Load power as a function of frequency; BGY115A, typical values.

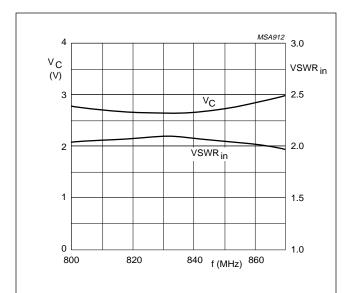


 $Z_S = Z_L = 50~\Omega;~P_D = 2~mW;~V_S = 6~V;~V_C = 3.5~V;~T_{mb} = 25~^{\circ}C.$

Fig.5 Load power as a function of mounting base temperature; BGY115A, typical values.

UHF amplifier modules

BGY115A; BGY115B; BGY115C/P; BGY115D



 Z_S = Z_L = 50 Ω ; P_D = 2 mW; P_L = 1.2 W; V_S = 6 V; T_{mb} = 25 °C.

Fig.6 Control voltage and VSWR input as functions of frequency; BGY115A, typical values.

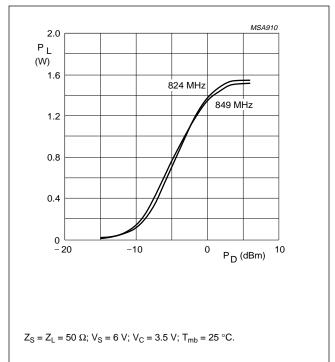


Fig.7 Load power as a function of drive power; BGY115A, typical values.

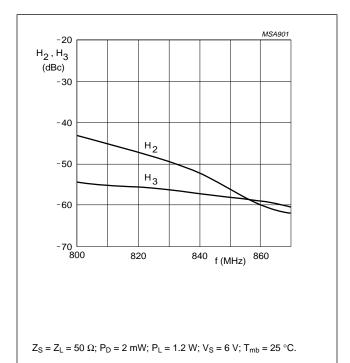
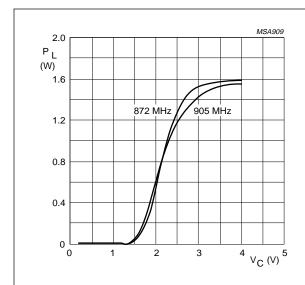


Fig.8 Harmonics as functions of frequency; BGY115A, typical values.

UHF amplifier modules

BGY115A; BGY115B; BGY115C/P; BGY115D



 Z_S = Z_L = 50 Ω ; P_D = 2 mW; V_S = 6 V; T_{mb} = 25 $^{\circ}C$.

Fig.9 Load power as a function of control voltage; BGY115B, typical values.

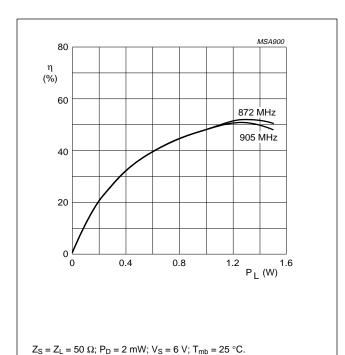
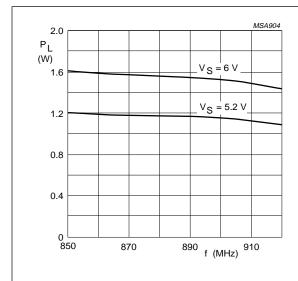
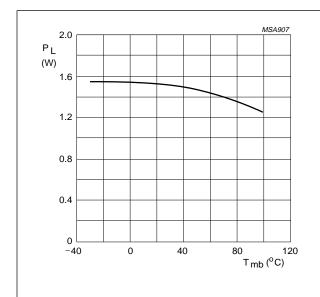


Fig.10 Efficiency as a function of load power; BGY115B, typical values.



 Z_S = Z_L = 50 $\Omega;$ P_D = 2 mW; V_C = 3.5 V; T_{mb} = 25 $^{\circ}C.$

Fig.11 Load power as a function of frequency; BGY115B, typical values.

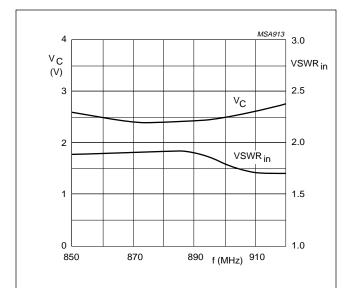


 Z_S = Z_L = 50 Ω ; P_D = 2 mW; V_S = 6 V; V_C = 3.5 V; f = 890 MHz.

Fig.12 Load power as a function of mounting base temperature; BGY115B, typical values.

UHF amplifier modules

BGY115A; BGY115B; BGY115C/P; BGY115D



 Z_S = Z_L = 50 $\Omega;$ P_D = 2 mW; P_L = 1.2 W; V_S = 6 V; T_{mb} = 25 $^{\circ}C.$

Fig.13 Control voltage and VSWR input as functions of frequency; BGY115B, typical values.

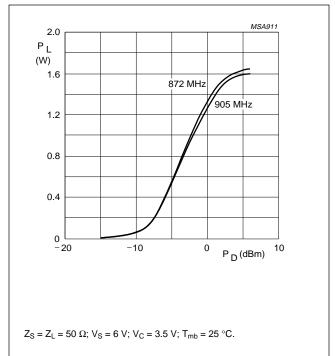
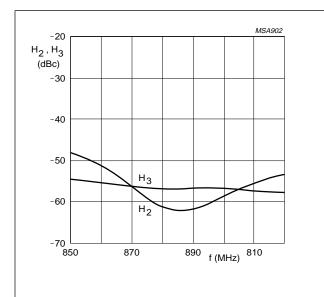


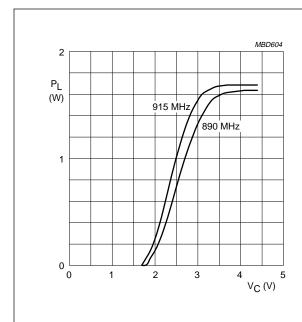
Fig.14 Load power as a function of drive power; BGY115B, typical values.



 Z_S = Z_L = 50 $\Omega;$ P_D = 2 mW; P_L = 1.2 W; V_S = 6 V; T_{mb} = 25 $^{\circ}C.$

Fig.15 Harmonics as functions of frequency; BGY115B, typical values.

UHF amplifier modules



 $Z_S = Z_L = 50~\Omega;~P_D = 2~mW;~V_S = 6~V;~T_{mb} = 25~^{\circ}C.$

Fig.16 Load power as a function of control voltage; BGY115C/P, typical values.

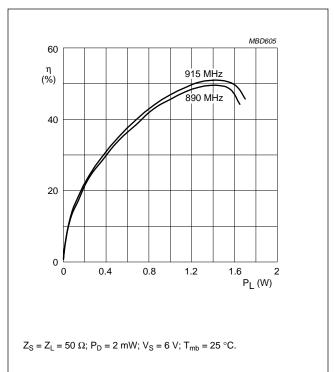
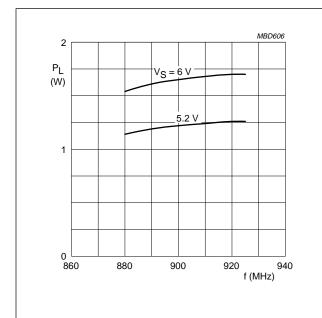


Fig.17 Efficiency as a function of load power; BGY115C/P, typical values.



 Z_{S} = Z_{L} = 50 $\Omega;$ P_{D} = 2 mW; V_{C} = 3.5 V; T_{mb} = 25 $^{\circ}C.$

Fig.18 Load power as a function of frequency; BGY115C/P, typical values.

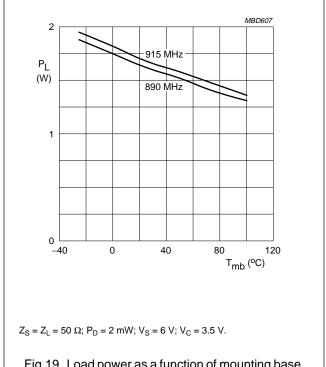


Fig.19 Load power as a function of mounting base temperature; BGY115C/P, typical values.

UHF amplifier modules

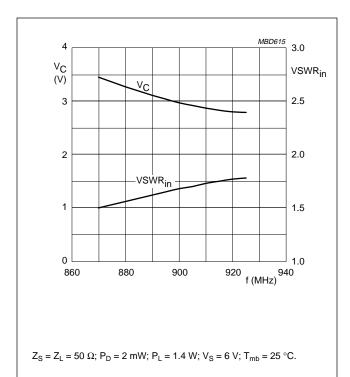


Fig.20 Control voltage and VSWR input as functions of frequency; BGY115C/P, typical values.

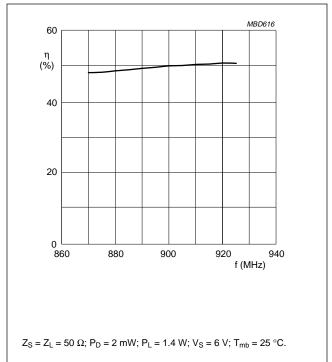
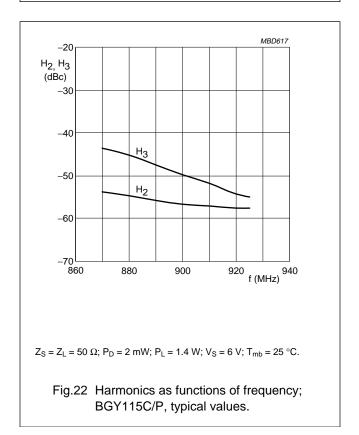
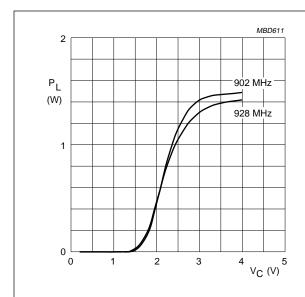


Fig.21 Efficiency as a function of frequency; BGY115C/P, typical values.



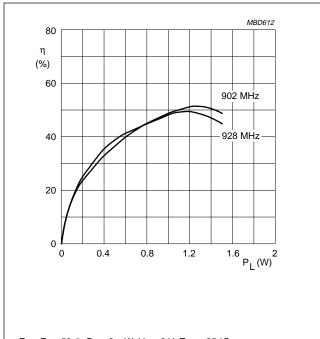
UHF amplifier modules

BGY115A; BGY115B; BGY115C/P; BGY115D



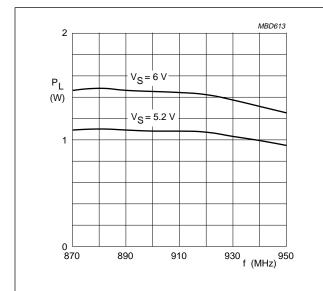
 Z_S = Z_L = 50 $\Omega;~P_D$ = 2 mW; V_S = 6 V; T_{mb} = 25 $^{\circ}C.$

Fig.23 Load power as a function of control voltage; BGY115D, typical values.



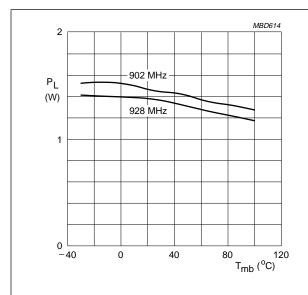
 $Z_S = Z_L = 50~\Omega;~P_D = 2~mW;~V_S = 6~V;~T_{mb} = 25~^{\circ}C.$

Fig.24 Efficiency as a function of load power; BGY115D, typical values.



 Z_S = Z_L = 50 $\Omega;$ P_D = 2 mW; V_C = 3.5 V; T_{mb} = 25 $^{\circ}C.$

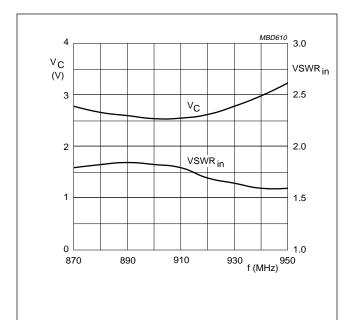
Fig.25 Load power as a function of frequency; BGY115D, typical values.



 $Z_S = Z_L = 50 \ \Omega; \ P_D = 2 \ mW; \ V_S = 6 \ V; \ V_C = 3.5 \ V.$

Fig.26 Load power as a function of mounting base temperature; BGY115D, typical values.

UHF amplifier modules



 Z_S = Z_L = 50 $\Omega;$ P_D = 2 mW; P_L = 1.2 W; V_S = 6 V; T_{mb} = 25 °C.

Fig.27 Control voltage and VSWR input as functions of frequency; BGY115D, typical values.

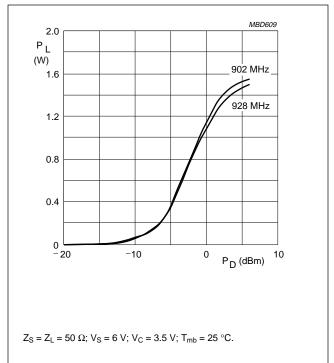


Fig.28 Load power as a function of drive power; BGY115D, typical values.

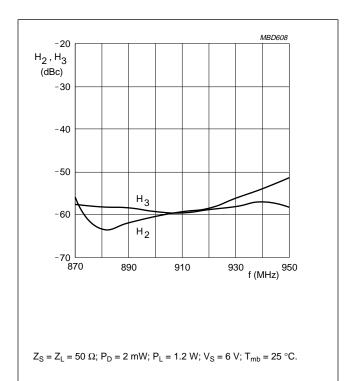
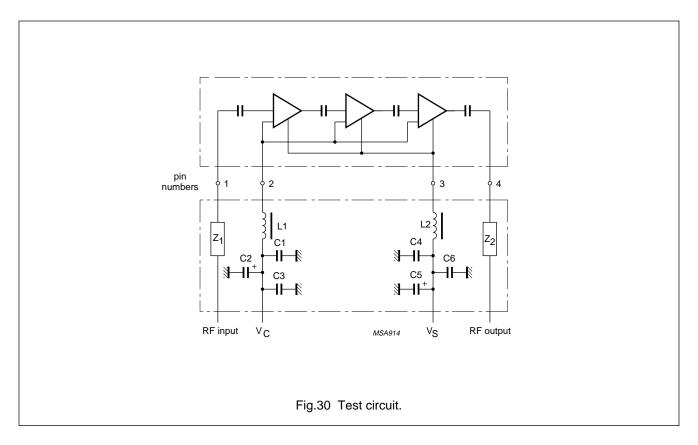
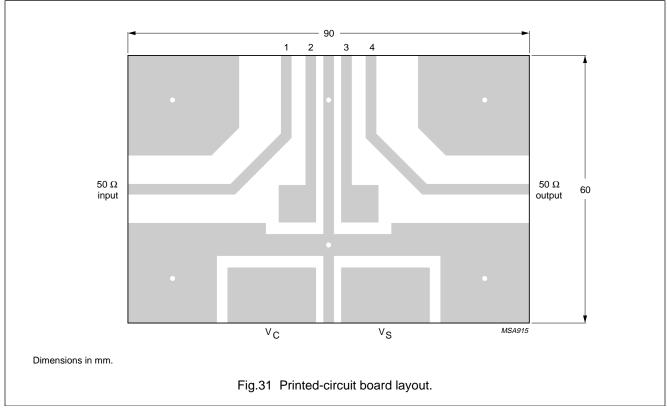


Fig.29 Harmonics as functions of frequency; BGY115D, typical values.

UHF amplifier modules





UHF amplifier modules

BGY115A; BGY115B; BGY115C/P; BGY115D

List of components (see Fig.30)

COMPONENT	DESCRIPTION	VALUE	CATALOGUE NO.
C1, C4	multilayer ceramic chip capacitor	100 nF	2222 852 47104
C2, C5	35 V tantalum capacitor	2.2 μF	-
C3, C6	multilayer ceramic chip capacitor	33 pF	2222 851 13339
L1, L2	Ferroxcube coil	5 μΗ	3122 108 20153
Z ₁ , Z ₂	stripline; note 1	50 Ω	_

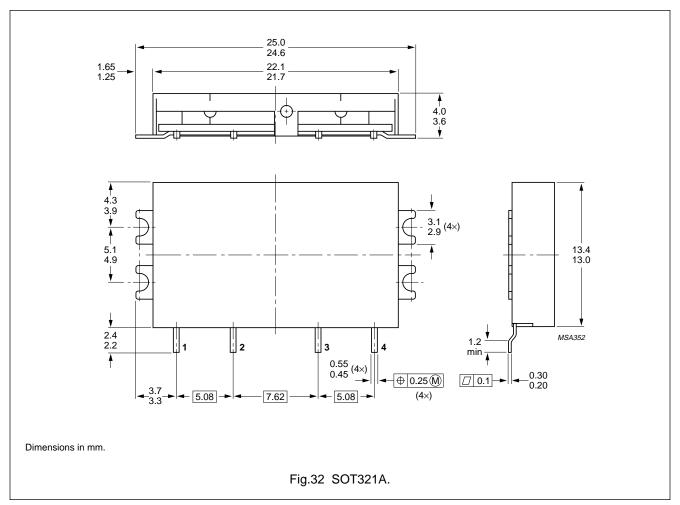
Note

1. The striplines are on a double copper-clad printed-circuit board with PTFE fibre-glass dielectric (ε_r = 2.2); thickness 1/32 inch.

UHF amplifier modules

BGY115A; BGY115B; BGY115C/P; BGY115D

PACKAGE OUTLINE



UHF amplifier modules

BGY115A; BGY115B; BGY115C/P; BGY115D

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

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